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PSMN020-30MLC

N-channel 30 V 18.1 mΩ logic level MOSFET in LFPAK33 using TrenchMOS Technology

4 September 2012 **Product data sheet**

1. Product profile

1.1 General description

Logic level enhancement mode N-channel MOSFET in LFPAK33 package. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

1.2 Features and benefits

- Low parasitic inductance and resistance
- Optimised for 4.5V Gate drive utilising Superjunction technology
- Ultra low QG, QGD, and QOSS for high system efficiencies at low and high loads

1.3 Applications

- DC-to-DC converters
- Load switching
- Synchronous buck regulator

1.4 Quick reference data

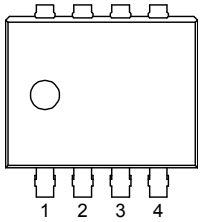
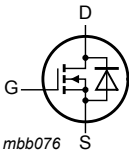
Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{DS}	drain-source voltage	T_j = 25 °C		-	-	30	V
I_D	drain current	T_{mb} = 25 °C; V_{GS} = 10 V; Fig. 1		-	-	31.8	A
P_{tot}	total power dissipation	T_{mb} = 25 °C; Fig. 2		-	-	33	W
T_j	junction temperature			-55	-	175	°C
Static characteristics							
R_{DSon}	drain-source on-state resistance	V_{GS} = 4.5 V; I_D = 5 A; T_j = 25 °C; Fig. 10		-	20.5	27	mΩ
		V_{GS} = 10 V; I_D = 5 A; T_j = 25 °C; Fig. 10		-	14.7	18.1	mΩ
Dynamic characteristics							
Q_{GD}	gate-drain charge	V_{GS} = 4.5 V; I_D = 5 A; V_{DS} = 15 V; Fig. 12; Fig. 13		-	1.7	-	nC
$Q_{G(tot)}$	total gate charge	V_{GS} = 4.5 V; I_D = 5 A; V_{DS} = 15 V; Fig. 12; Fig. 13		-	4.6	-	nC

nexperia

2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	 LFPAK33 (SOT1210)	
2	S	source		
3	S	source		
4	G	gate		
mb	D	mounting base; connected to drain		

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PSMN020-30MLC	LFPAK33	Plastic single ended surface mounted package (LFPAK33); 4 leads	SOT1210

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	T_j = 25 °C		-	30	V
V_{GS}	gate-source voltage			-20	20	V
I_D	drain current	V_{GS} = 10 V; T_{mb} = 25 °C; Fig. 1		-	31.8	A
		V_{GS} = 10 V; T_{mb} = 100 °C; Fig. 1		-	22.5	A
I_{DM}	peak drain current	pulsed; $t_p \leq 10$ µs; T_{mb} = 25 °C; Fig. 4		-	127	A
P_{tot}	total power dissipation	T_{mb} = 25 °C; Fig. 2		-	33	W
T_{stg}	storage temperature			-55	175	°C
T_j	junction temperature			-55	175	°C
$T_{sld(M)}$	peak soldering temperature			-	260	°C
V_{ESD}	electrostatic discharge voltage	MM (JEDEC JESD22-A115)		130	-	V
Source-drain diode						
I_S	source current	T_{mb} = 25 °C		-	27.4	A
I_{SM}	peak source current	pulsed; $t_p \leq 10$ µs; T_{mb} = 25 °C		-	127	A

Symbol	Parameter	Conditions		Min	Max	Unit
Avalanche ruggedness						
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 31 A; $V_{sup} \leq$ 30 V; R_{GS} = 50 Ω; unclamped; Fig. 3		-	7.7	mJ

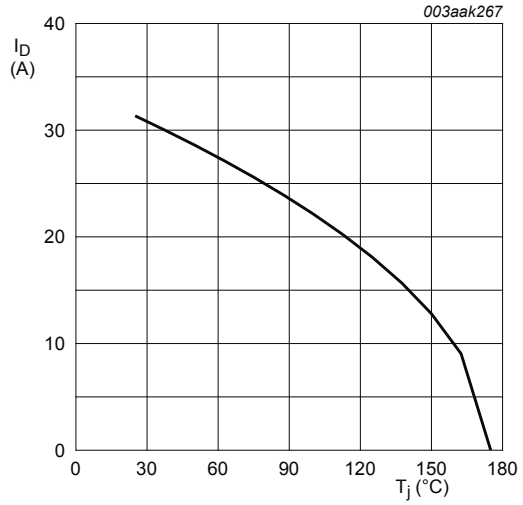


Fig. 1. Continuous drain current as a function of mounting base temperature

$V_{GS} \geq 10V$

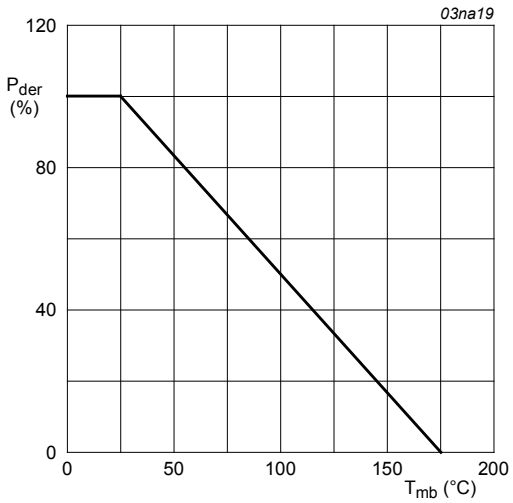


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25°C)}} \times 100\ \%$$

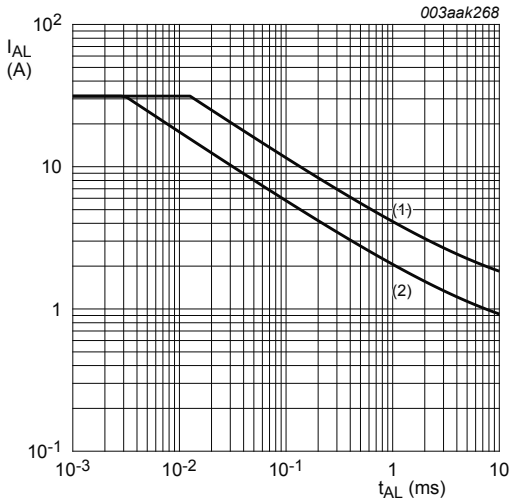


Fig. 3. Single pulse avalanche rating; avalanche current as a function of avalanche time

(1) $T_{j\ (init)} = 25°C$; (2) $T_{j\ (init)} = 100°C$

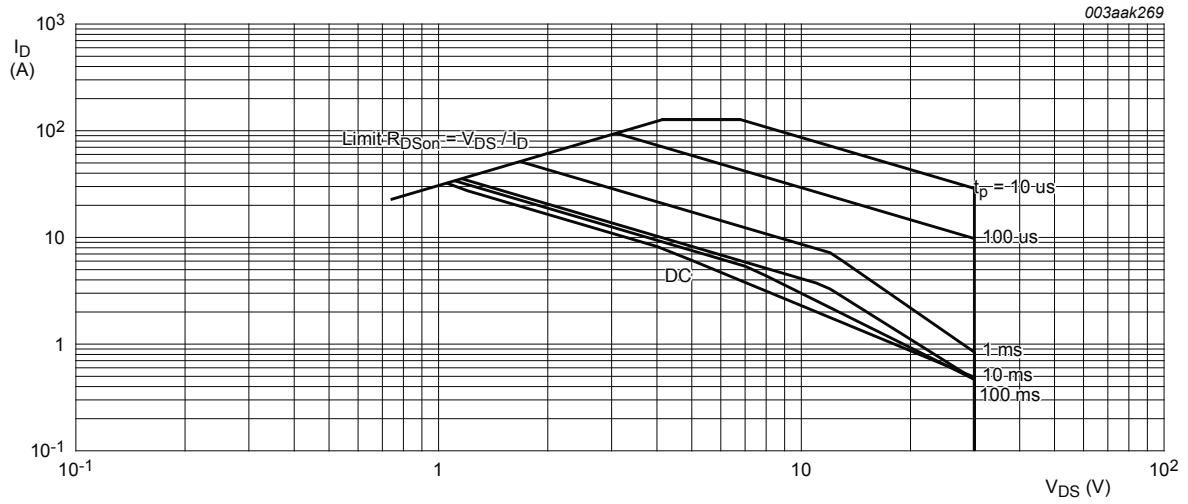


Fig. 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

$T_{mb} = 25°C;\ I_{DM}$ *is a single pulse*

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j\text{-}mb)}$	thermal resistance from junction to mounting base	Fig. 5		-	4.32	4.56	K/W

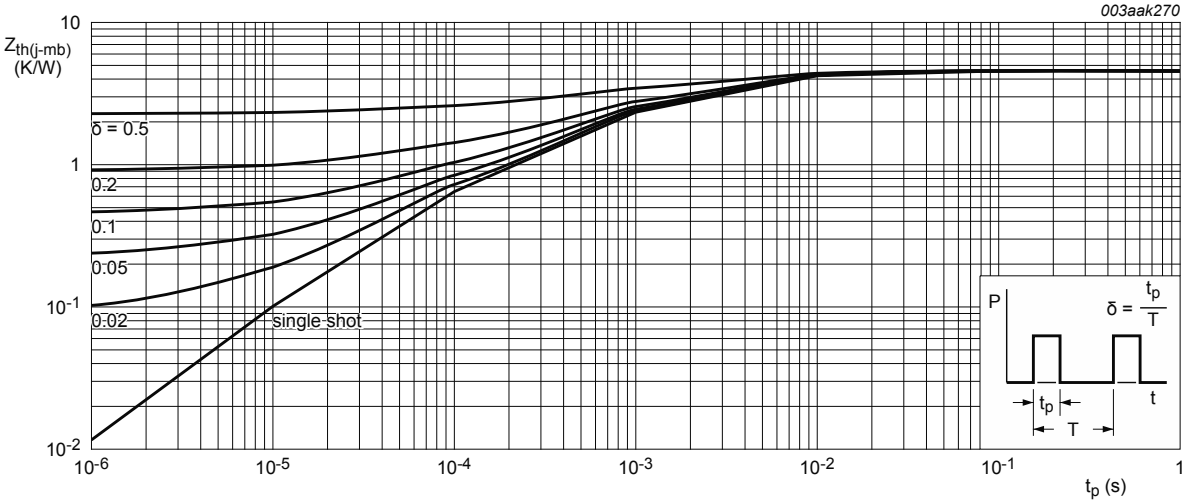


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Static characteristics							
$V_{(BR)DSS}$	drain-source breakdown voltage	I_D = 13.5 A; V_{GS} = 0 V; $T_{j(init)}$ = 25 °C; $t_p \leq 50$ µs		34	-	-	V
		I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C		30	-	-	V
		I_D = 250 µA; V_{GS} = 0 V; T_j = -55 °C		27	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	I_D = 1 mA; V_{DS} = V_{GS}; T_j = 25 °C		1.05	1.62	1.95	V
$\Delta V_{GS(th)}/\Delta T$	gate-source threshold voltage variation with temperature			-	-3.5	-	mV/K
I_{DSS}	drain leakage current	V_{DS} = 30 V; V_{GS} = 0 V; T_j = 25 °C		-	-	1	µA
		V_{DS} = 30 V; V_{GS} = 0 V; T_j = 150 °C		-	-	100	µA
I_{GSS}	gate leakage current	V_{GS} = 16 V; V_{DS} = 0 V; T_j = 25 °C		-	-	100	nA
		V_{GS} = -16 V; V_{DS} = 0 V; T_j = 25 °C		-	-	100	nA
R_{DSon}	drain-source on-state resistance	V_{GS} = 4.5 V; I_D = 5 A; T_j = 25 °C; Fig. 10		-	20.5	27	mΩ
		V_{GS} = 4.5 V; I_D = 5 A; T_j = 150 °C; Fig. 10; Fig. 11		-	-	43.2	mΩ
		V_{GS} = 10 V; I_D = 5 A; T_j = 25 °C; Fig. 10		-	14.7	18.1	mΩ
		V_{GS} = 10 V; I_D = 5 A; T_j = 150 °C; Fig. 10; Fig. 11		-	-	29	mΩ
R_G	gate resistance	f = 1 MHz		0.68	1.37	2.74	Ω
Dynamic characteristics							
$Q_{G(tot)}$	total gate charge	I_D = 5 A; V_{DS} = 15 V; V_{GS} = 10 V; Fig. 12; Fig. 13		-	9.5	-	nC
		I_D = 5 A; V_{DS} = 15 V; V_{GS} = 4.5 V; Fig. 12; Fig. 13		-	4.6	-	nC
		I_D = 0 A; V_{DS} = 0 V; V_{GS} = 10 V		-	8.4	-	nC
Q_{GS}	gate-source charge	I_D = 5 A; V_{DS} = 15 V; V_{GS} = 4.5 V; Fig. 12; Fig. 13		-	1	-	nC
$Q_{GS(th)}$	pre-threshold gate-source charge			-	0.3	-	nC
$Q_{GS(th-pl)}$	post-threshold gate-source charge			-	0.7	-	nC
Q_{GD}	gate-drain charge			-	1.7	-	nC
$V_{GS(pl)}$	gate-source plateau voltage	I_D = 5 A; V_{DS} = 15 V; Fig. 12; Fig. 13		-	2.4	-	V

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
C_{iss}	input capacitance	V_{DS} = 15 V; V_{GS} = 0 V; f = 1 MHz; T_j = 25 °C; Fig. 14		-	430	-	pF
C_{oss}	output capacitance			-	120	-	pF
C_{rss}	reverse transfer capacitance			-	70	-	pF
$t_{d(on)}$	turn-on delay time	V_{DS} = 15 V; R_L = 3 Ω; V_{GS} = 4.5 V; $R_{G(ext)}$ = 5 Ω		-	6.1	-	ns
t_r	rise time			-	7.2	-	ns
$t_{d(off)}$	turn-off delay time			-	10.1	-	ns
t_f	fall time			-	5.1	-	ns
Q_{oss}	output charge	V_{GS} = 0 V; V_{DS} = 15 V; f = 1 MHz; T_j = 25 °C		-	2.3	-	nC
Source-drain diode							
V_{SD}	source-drain voltage	I_S = 5 A; V_{GS} = 0 V; T_j = 25 °C; Fig. 15		-	0.89	1.1	V
t_{rr}	reverse recovery time	I_S = 5 A; dI_S/dt = -100 A/µs; V_{GS} = 0 V; V_{DS} = 15 V		-	13.5	-	ns
Q_r	recovered charge			-	5.1	-	nC
t_a	reverse recovery rise time	V_{GS} = 0 V; I_S = 5 A; dI_S/dt = -100 A/µs; V_{DS} = 15 V; Fig. 16		-	6.3	-	ns
t_b	reverse recovery fall time			-	7.2	-	ns

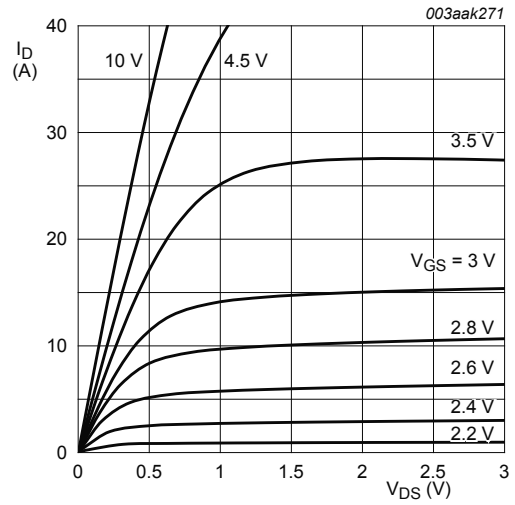


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values

$T_j = 25°C$

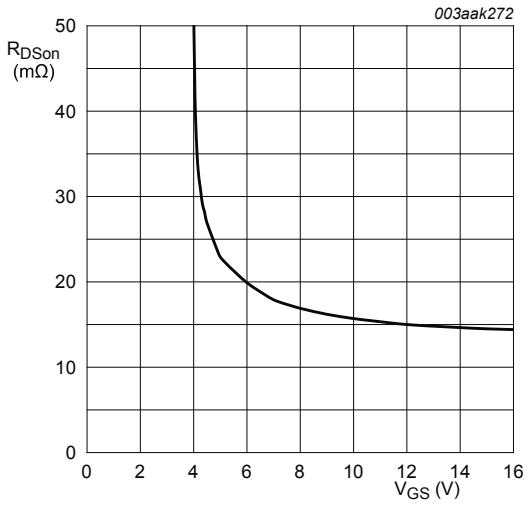


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$T_j = 25°C;\ I_D = 10A$

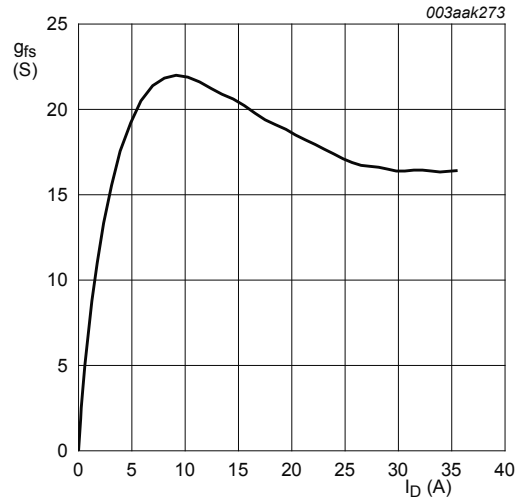


Fig. 8. Forward transconductance as a function of drain current; typical values

$T_j = 25°C;\ V_{DS} = 10V$

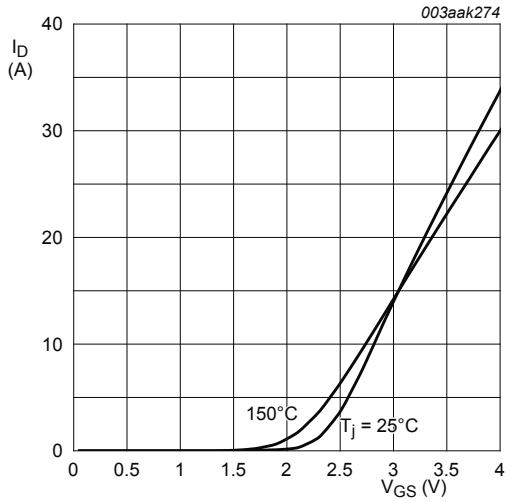


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$V_{DS} = 10V$

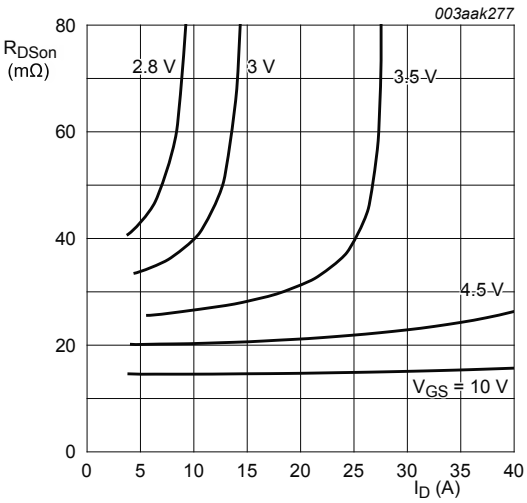


Fig. 10. Drain-source on-state resistance as a function of drain current; typical values

$T_j = 25°C$

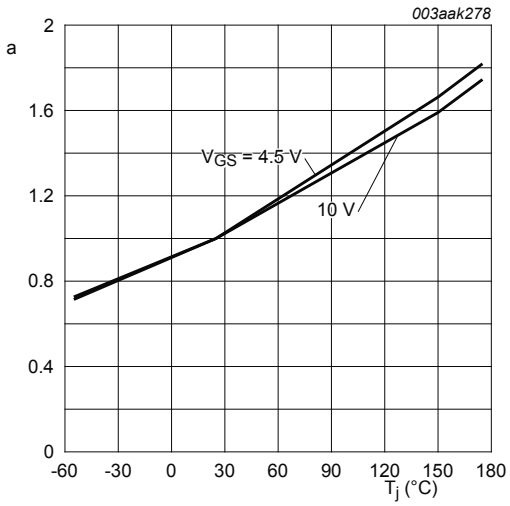


Fig. 11. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon\,(25°C)}}$$

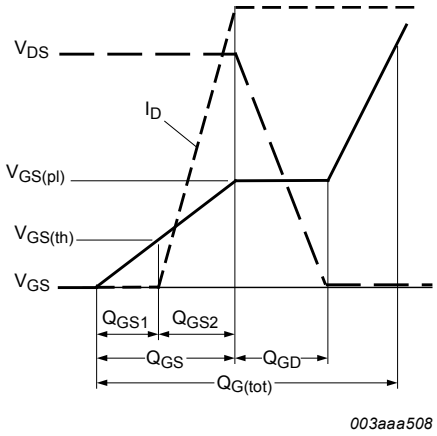


Fig. 12. Gate charge waveform definitions

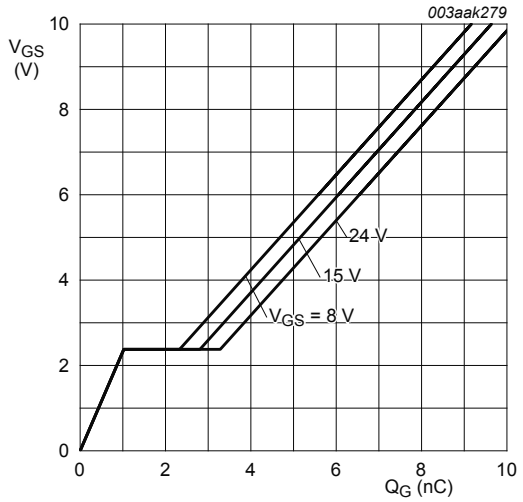


Fig. 13. Gate-source voltage as a function of gate charge; typical values

$T_j = 25°C;\ I_D = 10A$

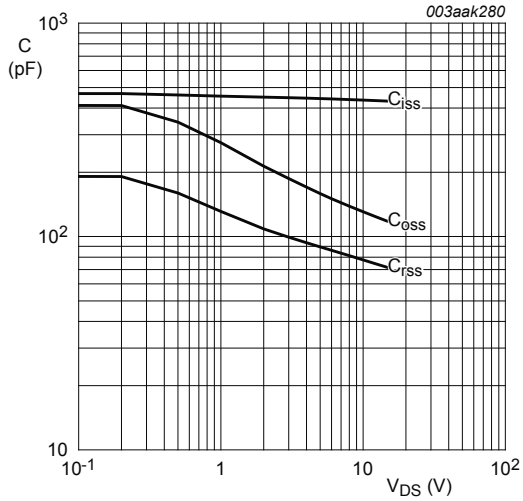


Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$V_{GS} = 0V;\ f = 1MHz$

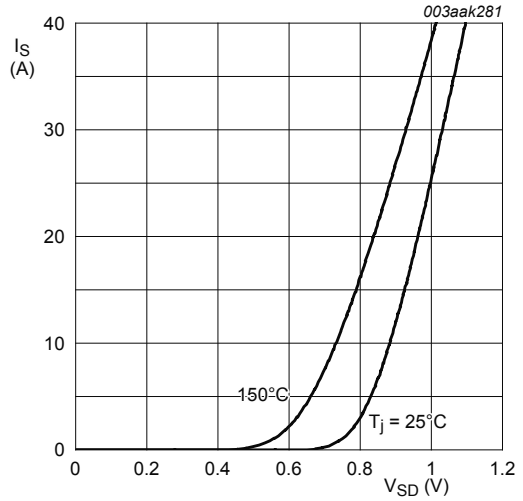


Fig. 15. Source current as a function of source-drain voltage; typical values

$V_{GS} = 0V$

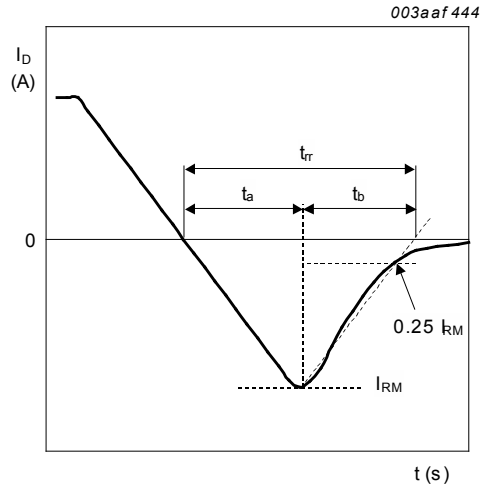
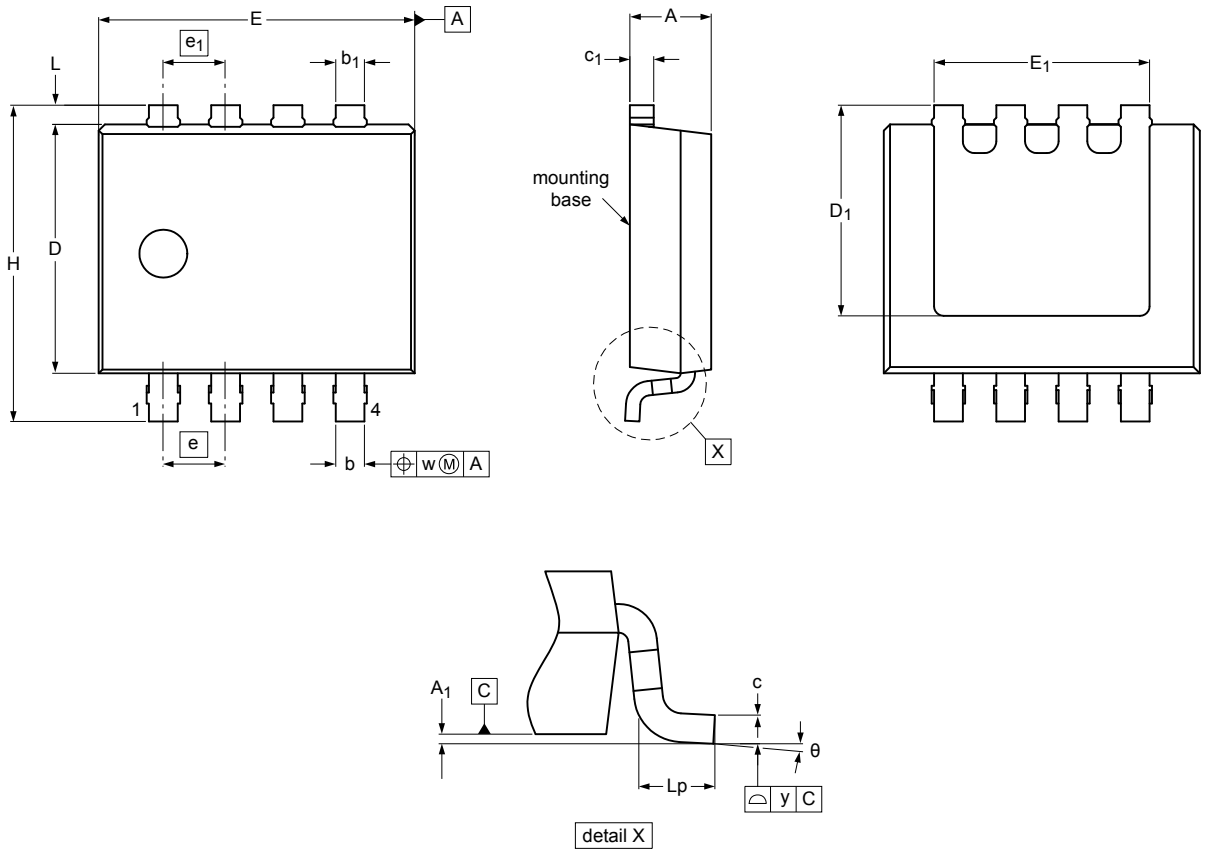
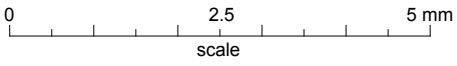


Fig. 16. Reverse recovery timing definition

7. Package outline

Plastic single ended surface mounted package (LFPAK33); 8 leads **SOT1210**





Dimensions

Unit[1]		A	A_1	b	b_1	c	c_1	$D^{(1)}$	D_1	$E^{(1)}$	E_1	e	e_1	H	L	L_p	w	y	θ
mm	max	0.90	0.10	0.35	0.35	0.20	0.30	2.70	2.35	3.40	2.45			3.40	0.25	0.50			8°
	nom											0.65	0.65				0.20	0.10	
	min	0.80	0.00	0.25	0.25	0.10	0.20	2.50	1.90	3.20	2.00			3.20	0.13	0.30			0°

Note
1. Plastic or metal protrusions of 0.15 mm per side are not included.

sot1210_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1210						~~11-12-19~~ 12-03-12

Fig. 17. Package outline LFPAK33 (SOT1210)

8. Legal information

8.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.
[2] The term 'short data sheet' is explained in section "Definitions".
[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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9. Contents

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